

International IOR Rectifier

UFB60FA40

Insulated Ultrafast Rectifier Module

Features

- Two Fully Independent Diodes
- Ceramic Fully Insulated Package ($V_{ISOL} = 2500V$ AC)
- Ultrafast Reverse Recovery
- Ultrasoft Reverse Recovery Current Shape
- Low Forward Voltage
- Optimized for Power Conversion: Welding and Industrial SMPS Applications
- Industry Standard Outline
- Plug-in Compatible with other SOT-227 Packages
- Easy to Assemble
- Direct Mounting to Heatsink

$t_{rr} = 46ns$
$I_{F(AV)} = 60A$
@ $T_C = 90^\circ C$
$V_R = 400V$

Description

The UFB60FA40 insulated modules integrate two state-of-the-art International Rectifier's Ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The planar structure of the diodes, and the platinum doping life-time control, provide a Ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

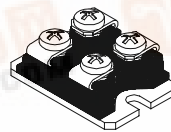
These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of Welding machines, SMPS, DC-DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/ RFI.

Absolute Maximum Ratings

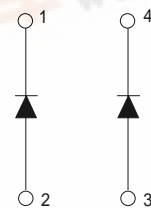
Parameters		Max	Units
V_R	Cathode-to-Anode Voltage	400	V
I_F	Continuous Forward Current, $T_C = 90^\circ C$	30	A
I_{FSM}	Single Pulse Forward Current, $T_C = 25^\circ C$	250	
P_D	Max. Power Dissipation, $T_C = 90^\circ C$	64	W
V_{ISOL}	RMS Isolation Voltage, Any Terminal to Case, $t = 1$ min	2500	V
T_J, T_{STG}	Operating Junction and Storage Temperatures	- 55 to 150	$^\circ C$

Case Styles

UFB60FA40



SOT-227



Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified) per diode

Parameters		Min	Typ	Max	Units	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	400	-	-	V	$I_R = 100\mu\text{A}$
V_{FM}	Forward Voltage	-	1.13	1.39	V	$I_F = 30\text{A}$
		-	0.93	1.07	V	$I_F = 30\text{A}, T_J = 150^\circ\text{C}$
I_{RM}	Reverse Leakage Current	-	-	100	μA	$V_R = V_R \text{ Rated}$
		-	-	1.0	mA	$T_J = 150^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T	Junction Capacitance	-	68	-	pF	$V_R = 400\text{V}$

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified) per diode

Parameters		Min	Typ	Max	Units	Test Conditions	
t_{rr}	Reverse Recovery Time	-	32	46	ns	$I_F = 1.0\text{A}, di_F/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$	
		-	67	-		$T_J = 25^\circ\text{C}$	$I_F = 30\text{A}$ $V_R = 200\text{V}$ $di_F/dt = 200\text{A}/\mu\text{s}$
		-	120	-		$T_J = 125^\circ\text{C}$	
I_{RRM}	Peak Recovery Current	-	6.8	-	A	$T_J = 25^\circ\text{C}$	
		-	15	-		$T_J = 125^\circ\text{C}$	
Q_{rr}	Reverse Recovery Charge	-	228	-	nC	$T_J = 25^\circ\text{C}$	
		-	900	-		$T_J = 125^\circ\text{C}$	

Thermal - Mechanical Characteristics

Parameters		Min	Typ	Max	Units
R_{thJC}	Junction to Case, Single Leg Conducting	-	-	1.9	$^\circ\text{C}/\text{W}$
	Both Leg Conducting	-	-	0.95	K/W
R_{thCS}	Case to Heat Sink, Flat, Greased Surface	-	0.05	-	
Wt	Weight	-	30	-	g
T	Mounting Torque	-	1.3	-	(N*m)

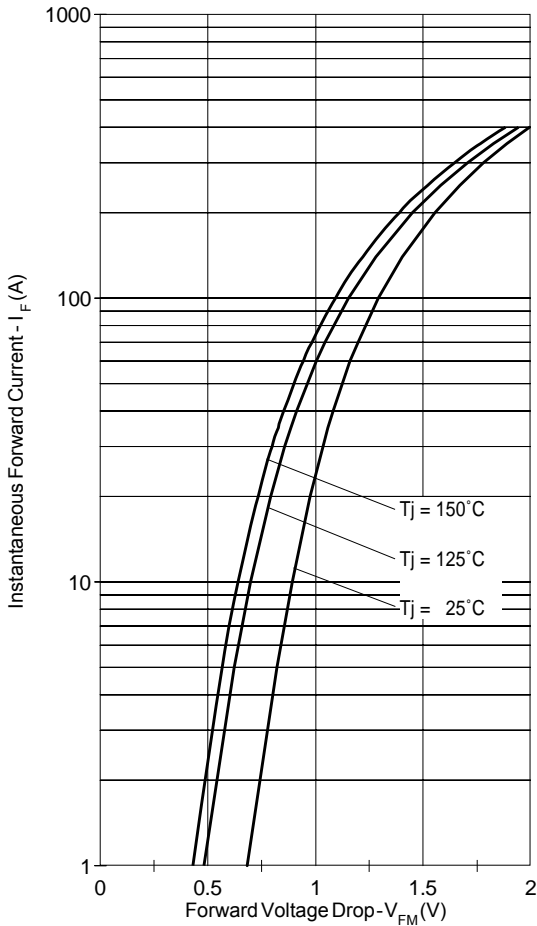


Fig. 1 - Typical Forward Voltage Drop Characteristics (per diode)

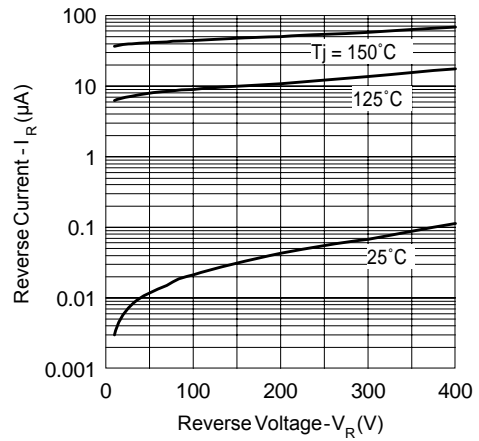


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

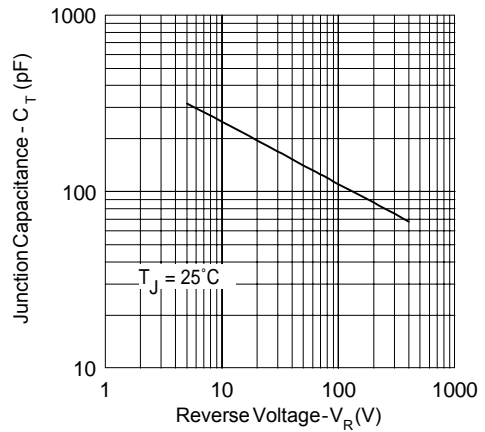


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

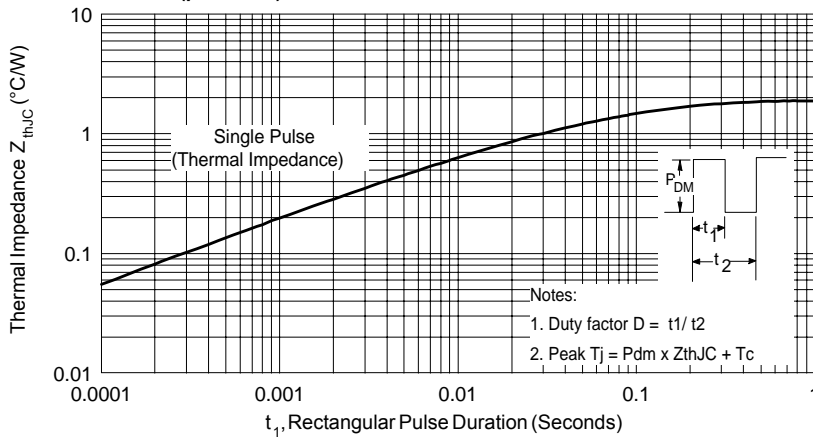


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics (per diode)

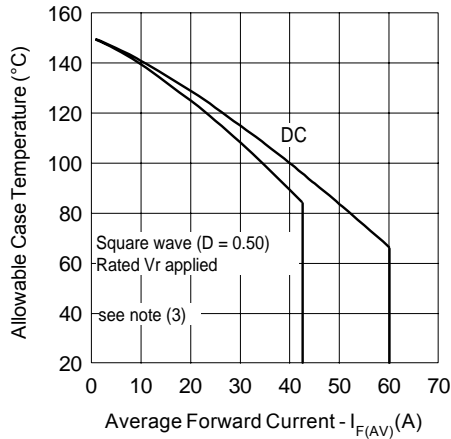


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current (per leg)

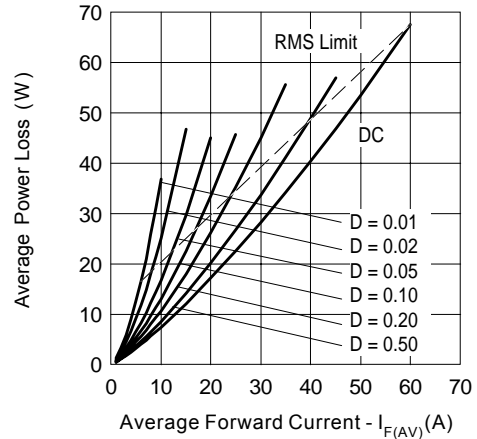


Fig. 6 - Forward Power Loss Characteristics (per leg)

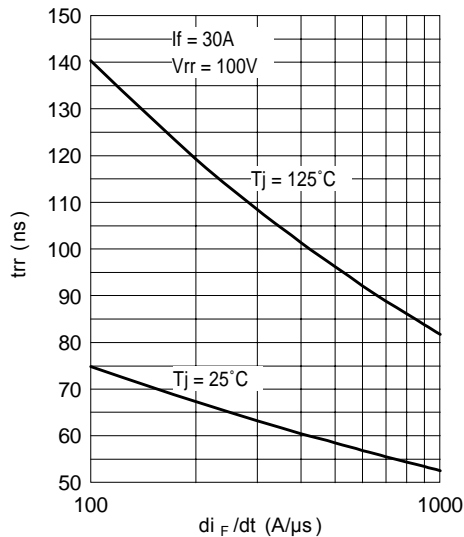


Fig. 7 - Typical Reverse Recovery time vs. di_F/dt

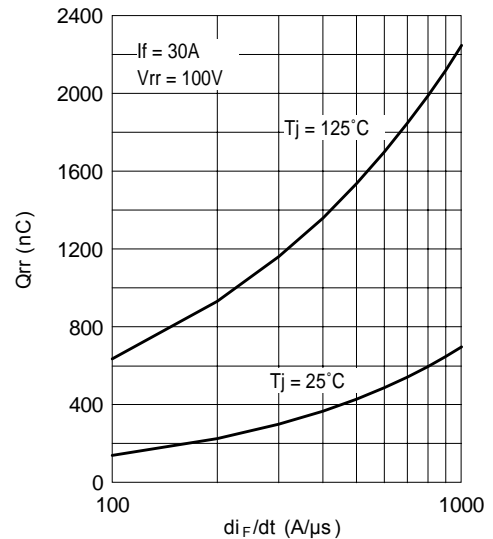
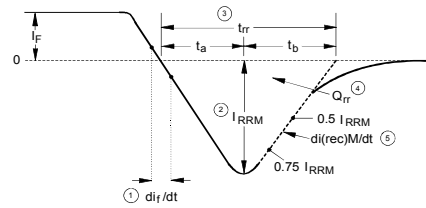
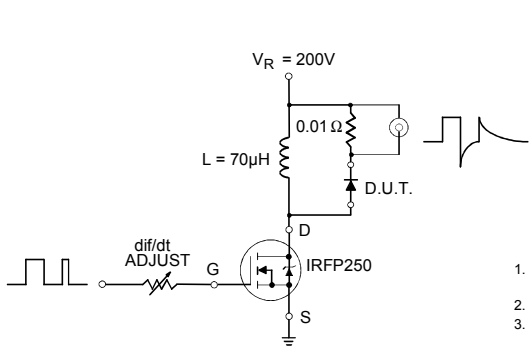


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$



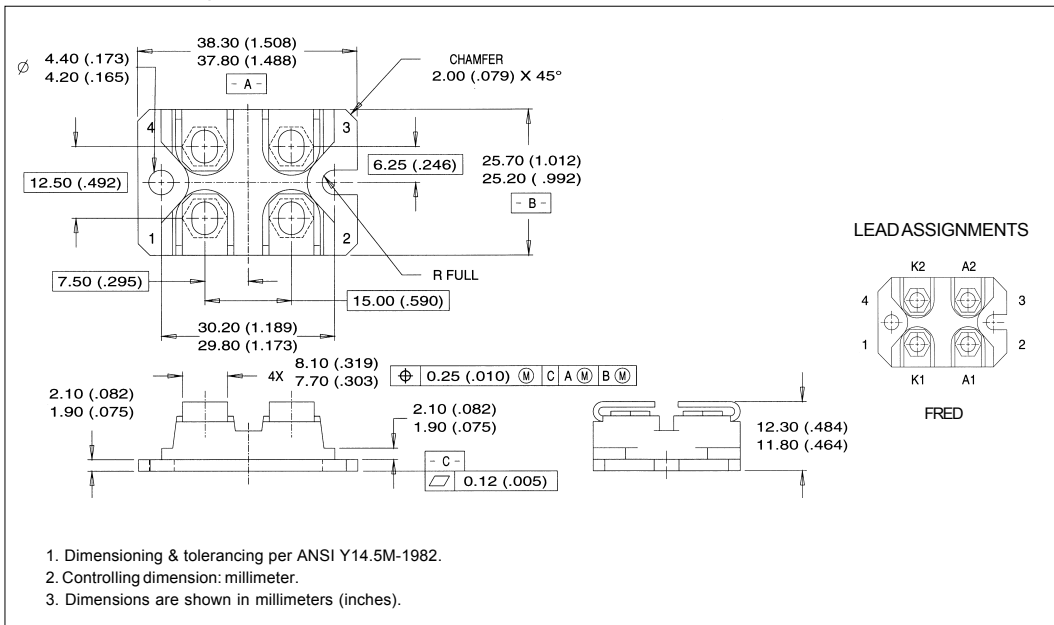
1. di_f/dt - Rate of change of current through zero crossing
2. I_{RRM} - Peak reverse recovery current
3. t_{rr} - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current
4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$
5. $di_{(rec)M}/dt$ - Peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

SOT-227 Package Details



UFB60FA40

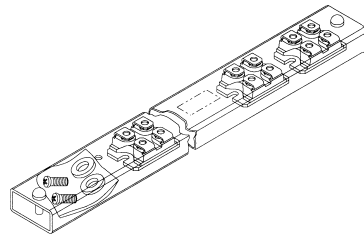
Bulletin PD-20779 03/02

International
IR Rectifier

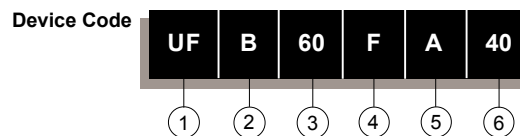
SOT-227 Package Details

Tube

QUANTITY PER TUBE IS 10
M4 SCREW AND WASHER INCLUDED



Ordering Information Table



- 1** - ULTRAFAST RECTIFIER
- 2** - Ultrafast Pt diffused
- 3** - Current Rating (60 = 60A)
- 4** - Circuit Configuration (2 separate Diodes, parallel pin-out)
- 5** - Package Indicator (SOT-227 Standard Isolated Base)
- 6** - Voltage Rating (40 = 400V)

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/02